

MPS2369

SILICON
NPN TRANSISTOR



TO-92 CASE

Central
Semiconductor Corp.

www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR MPS2369 is a silicon epitaxial planar NPN transistor designed for ultra high speed saturated switching applications.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Collector-Base Voltage
Collector-Emitter Voltage
Collector-Emitter Voltage
Emitter-Base Voltage
Continuous Collector Current
Power Dissipation
Operating and Storage Junction Temperature
Thermal Resistance

SYMBOL		UNITS
V_{CBO}	40	V
V_{CES}	40	V
V_{CEO}	15	V
V_{EBO}	4.5	V
I_C	200	mA
P_D	625	mW
T_J, T_{stg}	- 55 to +150	$^\circ\text{C}$
θ_{JA}	200	$^\circ\text{C/W}$

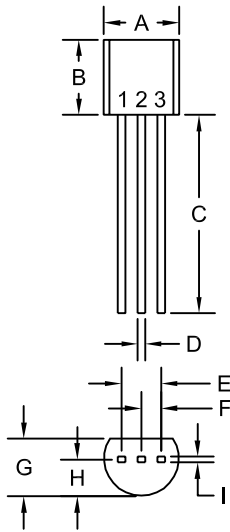
ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_{CBO}	$V_{CB}=20\text{V}$			400	nA
I_{CBO}	$V_{CB}=20\text{V}, T_A=125^\circ\text{C}$			30	μA
I_{CES}	$V_{CE}=20\text{V}$			400	nA
BV_{CBO}	$I_C=10\mu\text{A}$	40			V
BV_{CES}	$I_C=10\mu\text{A}$	40			V
BV_{EBO}	$I_E=10\mu\text{A}$	4.5			V
$V_{CE(SAT)}$	$I_C=10\text{mA}, I_B=1.0\text{mA}$			250	mV
$V_{BE(SAT)}$	$I_C=10\text{mA}, I_B=1.0\text{mA}$	700		850	mV
h_{FE}	$V_{CE}=1.0\text{V}, I_C=10\text{mA}$	40		120	
h_{FE}	$V_{CE}=1.0\text{V}, I_C=10\text{mA}, T_A=-55^\circ\text{C}$	20			
h_{FE}	$V_{CE}=2.0\text{V}, I_C=100\text{mA}$	20			
C_{ob}	$V_{CB}=5.0\text{V}, I_E=0, f=1.0\text{MHz}$			4.0	pF
f_T	$V_{CE}=10\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	500			MHz
t_s	$V_{CC}=3.0\text{V}, I_C=10\text{mA}, I_{B1}=I_{B2}=10\text{mA}$		5.0	13	ns
t_{on}	$V_{CC}=3.0\text{V}, I_C=10\text{mA}, I_{B1}=3.0\text{mA}$		8.0	12	ns
t_{off}	$V_{CC}=3.0\text{V}, I_C=10\text{mA}, I_{B1}=3.0\text{mA}, I_{B2}=1.5\text{mA}$		10	18	ns

MP2369A
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TO-92 CASE - MECHANICAL OUTLINE



R1

DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A (DIA)	0.175	0.205	4.45	5.21
B	0.170	0.210	4.32	5.33
C	0.500	-	12.70	-
D	0.016	0.022	0.41	0.56
E	0.100		2.54	
F	0.050		1.27	
G	0.125	0.165	3.18	4.19
H	0.080	0.105	2.03	2.67
I	0.015		0.38	

TO-92 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

MARKING: FULL PART NUMBER

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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